



PARA LIGHT ELECTRONICS CO., LTD.

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# DATA SHEET

# PART NO.: L-51ROPT1C

REV: <u>A/0</u>

CUSTOMER'S APPROVAL :

DCC:

DRAWING NO. : DS-G-21-17-0001

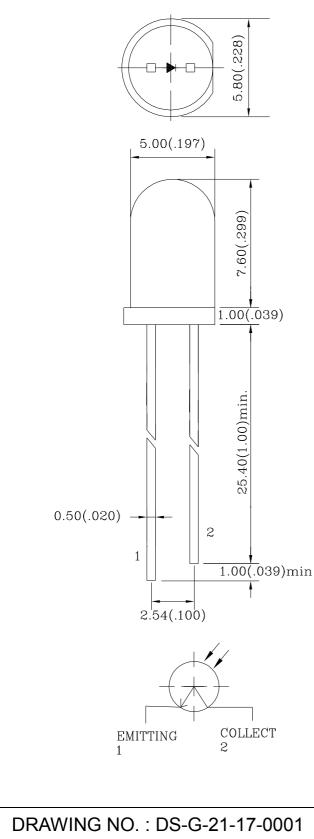
DATE: 2017-07-06

## L-51ROPT1C

REV:A/0

Release by PARALIGHTDCC

### PACKAGE DIMENSIONS



| ITEM       | MATERIALS             |
|------------|-----------------------|
| RESIN      | Epoxy Resin           |
| LEAD FRAME | Sn Plating iron Alloy |

Note:

1.All Dimensions are in millimeters.

- 2.Tolerance is ±0.25mm(0.010 ") Unless otherwise specified.
- 3.Protruded resin under flange is 1.5mm(0.059 ") max.

DATE : 2017-07-06



## L-51ROPT1C

#### REV:A/0

#### FEATURES

PARA ight

- \* High-brightness
- \* High reliability
- \* Low-voltage characteristics
- \* Pb FREE Products
- \* RoHS Compliant

#### CHIP MATERIALS

\* SILICON

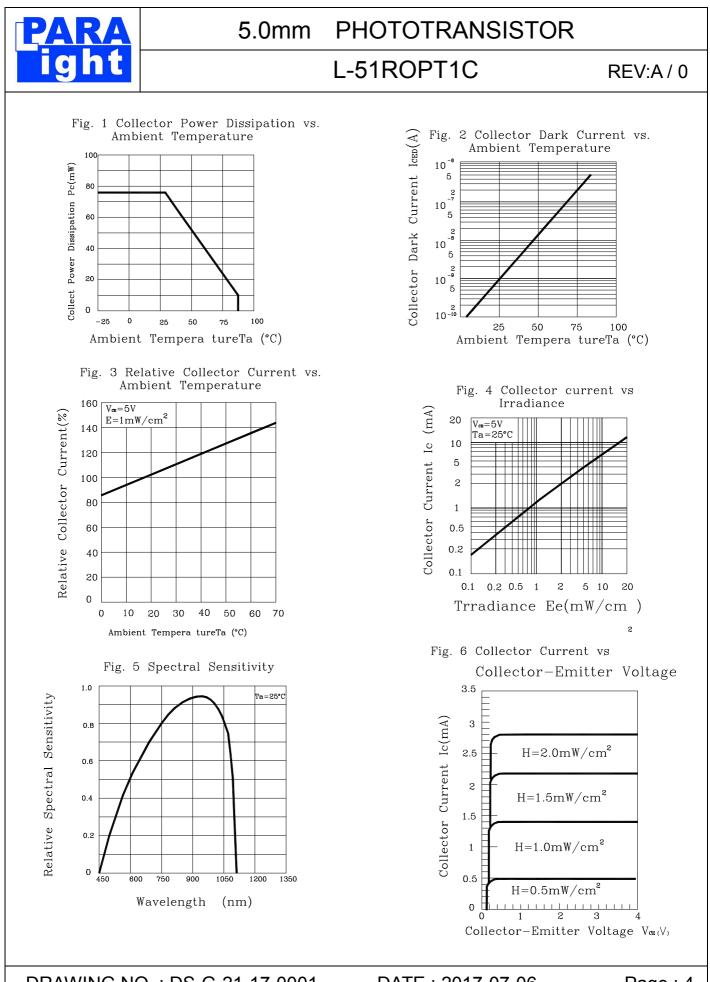
#### ABSOLUTE MAXIMUM RATING : ( Ta = 25°C )

| SYMBOL               | PARAMETER                           | MAX           | UNIT |
|----------------------|-------------------------------------|---------------|------|
| PD Power Dissipation |                                     | 10            | mW   |
| V(BR)CEO             | Collector-Emitter Breakdown Voltage | 30            | V    |
| Topr                 | Operating Temperature Range         | -35°C to 85°C |      |
| Tstg                 | Storage Temperature Range           | -35°C to 85°C |      |

#### ELECTRO-OPTICAL CHARACTERISTICS : ( $Ta = 25^{\circ}C$ )

| SYMBOL | PARAMETER                            | TEST<br>CONDITION                       | MIN. | TYP.  | MAX. | UNIT |
|--------|--------------------------------------|-----------------------------------------|------|-------|------|------|
| BVCEO  | Collector-Emitter Breakdown Voltage  | Ic = 100μA<br>Ee = 0 mw/cm <sup>2</sup> | 30   |       |      | V    |
| BVECO  | Emitter-Collector Breakdown Voltage  | IE=100μA<br>Ee= 0 mw/cm <sup>2</sup>    | 5    |       |      | V    |
| ICEO   | Collector Dark Current               | VCE=20V<br>Ee=0 mw/cm <sup>2</sup>      |      |       | 100  | nA   |
| VCE(S) | Collector-Emitter Saturation Voltage | IC=2mA<br>Ee=0.5<br>mw/cm <sup>2</sup>  |      |       | 0.4  | V    |
| Tr/Tf  | Rise / Fall Time                     | VCE=5V<br>IC=1mA<br>RL=1000 Ω           |      | 15/15 |      | uS   |
| IC     | On Stat Collector Current            | VCE=5V<br>Ee=0.1<br>mw/cm <sup>2</sup>  | 1.6  | 2     | 5.6  | mA   |
| λ      | Spectral Sensitivity Wavelength      |                                         |      | 940   |      | nm   |

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## Label Explanation

| ight                                                                                                                                                                                  |          | 子股份有<br>T ELECTRON |                 |         |  |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|----------|--------------------|-----------------|---------|--|
| PART                                                                                                                                                                                  |          |                    |                 |         |  |
| LOT NO                                                                                                                                                                                | <u> </u> |                    | INSPECTED       |         |  |
| BIN                                                                                                                                                                                   |          | Daa                | _               |         |  |
|                                                                                                                                                                                       | TY :     | PCS                | _               |         |  |
| N. W                                                                                                                                                                                  | •        | g                  |                 |         |  |
| PART NO.: L-51ROPT1C<br>Refer to page 12<br>LOT NO.: E L L 4 7 0009<br>A B C D E F<br>AE: For series number<br>BL: Local F: Foreign<br>CL: LAMP<br>DYear<br>EMonth<br>F Serial number |          |                    |                 |         |  |
| IC BIN<br>测试条件                                                                                                                                                                        |          |                    | 测试项目            |         |  |
| Ee=0,Ic=100µA,5ms                                                                                                                                                                     |          | 集-射核               | 集-射极崩溃电压 Vceo   |         |  |
| Ee=0,Ie=100µA,5ms                                                                                                                                                                     |          | 射-集橋               | 射-集极崩溃电压 Veco   |         |  |
| Ee=0,Vce=10V,5ms                                                                                                                                                                      |          | 集-射                | 集-射极暗漏电流 Iceo   |         |  |
| Ee=0.1mw/cm <sup>2</sup> ,Vce=5V                                                                                                                                                      |          | 集-射极               | 集-射极光电流 Ic,C 等级 |         |  |
| Ee=0.1mw/cm <sup>2</sup> ,Vce=5V                                                                                                                                                      |          | 集-射极               | 集-射极光电流 Ic,D 等级 |         |  |
| Ee=0.1mw/cm <sup>2</sup> ,Vce=5V                                                                                                                                                      |          | 集-射极               | 集-射极光电流 Ic,E 等级 |         |  |
| Ee=0.1mw/cm <sup>2</sup> ,Vce=5V                                                                                                                                                      |          | 集-射极               | 集-射极光电流 Ic,F 等级 |         |  |
| -                                                                                                                                                                                     |          | ·                  |                 | · · · · |  |

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分 BIN 要求

Vceo>30V

Veco>5V

 $Iceo{\leq}0.1\mu A$ 

1.6-2.6mA

2.6-3.6mA

3.6-4.6mA

4.6-5.6mA



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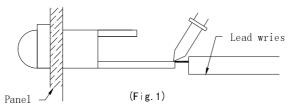
### •SOLDERING

0

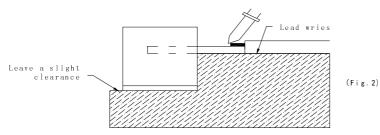
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| METHOD            | SOLDERING CONDITIONS                                                                                         | REMARK                                                                                                                                                                                                                      |  |  |
|-------------------|--------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|--|
| DIP<br>SOLDERING  | Bath temperature: 260℃<br>Immersion time: with 5 sec, 1 time                                                 | <ul> <li>Solder no closer than 3mm from the base of the package</li> <li>Using soldering flux," RESIN FLUX" is recommended.</li> </ul>                                                                                      |  |  |
| SOLDERING<br>IRON | Soldering iron: 30W or smaller<br>Temperature at tip of iron: 260℃ or lower<br>Soldering time: within 5 sec. | <ul> <li>During soldering, take care not to press the tip of iron against the lead.</li> <li>(To prevent heat from being transferred directly to the lead, hold the lead with a pair of tweezers while soldering</li> </ul> |  |  |

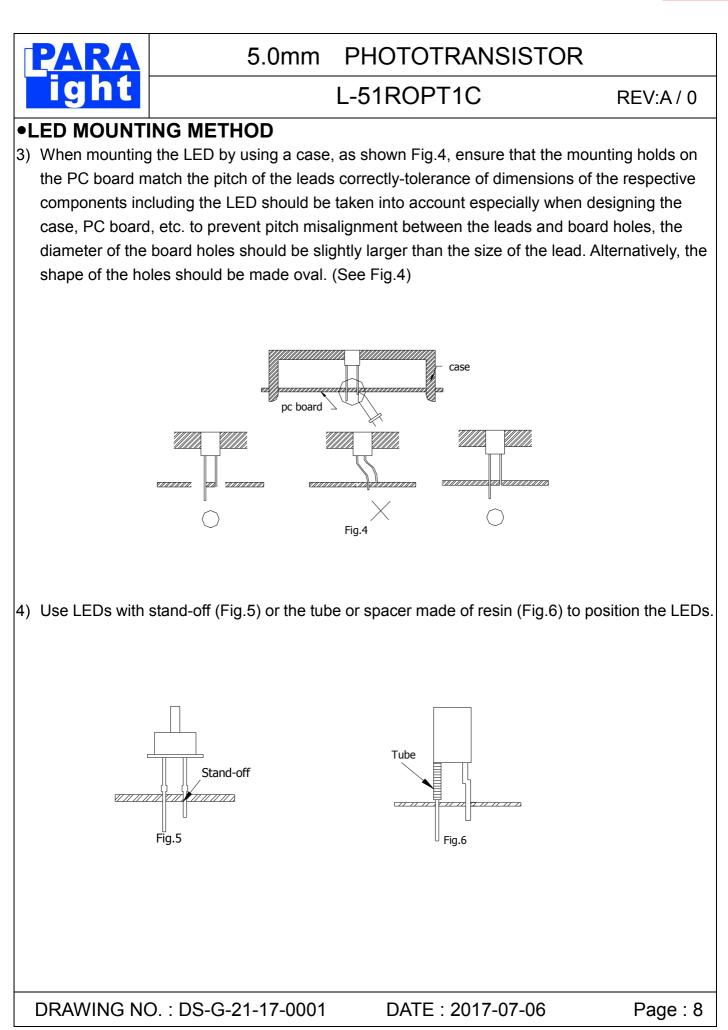
 When soldering the lead of LED in a condition that the package is fixed with a panel (See Fig.1), be careful not to stress the leads with iron tip.



2) When soldering wire to the lead, work with a Fig (See Fig.2) to avoid stressing the package.



Regarding solution in the tinning oven for product-tinning, compound sub-solution made of tin & copper and sliver is proposed with the temperature of Celsius 260. The proportion of the alloyed solution is tin 95.5: copper 3.5: silver 0.5 by percentage. The time of tinning is constantly 3 seconds.





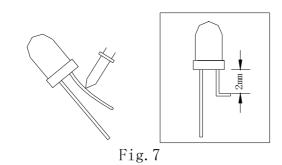


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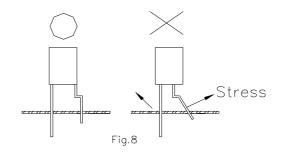
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#### •FORMED LEAD

1) The lead should be bent at a point located at least 2mm away from the package. Bending should be performed with base fixed means of a jig or pliers (Fig.7)



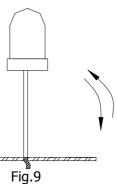
- 2) Forming lead should be carried our prior to soldering and never during or after soldering.
- Form the lead to ensure alignment between the leads and the hole on board, so that stress against the LED is prevented. (Fig.8)



#### •LEAD STRENGTH

1) Bend strength

Do not bend the lead more than twice. (Fig.9)



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Tensile strength (@Room Temperature)
 If the force is 1kg or less, there will be no problem. (Fig.10)



### • HEAT GENERATION

1) Thermal design of the end product is of paramount importance. Please consider the heat generation of the LED when making the system design. The coefficient of temperature increase per input electric power is affected by the thermal resistance of the circuit board and density of LED placement on the board, as well as other components. It is necessary to avoid intense heat generation and operate within the maximum ratings given in this specification.

The operating current should be decided after considering the ambient maximum temperature of LEDs.

### •CHEMICAL RESISTANCE

- 1) Avoid exposure to chemicals as it may attack the LED surface and cause discoloration.
- 2) When washing is required, refer to the following table for the proper chemical to be sued. (Immersion time: within 3 minutes at room temperature.)

| SOLVENT                             | ADAPTABILITY |  |
|-------------------------------------|--------------|--|
| Freon TE                            | $\odot$      |  |
| Chlorothene                         | $\times$     |  |
| Isopropyl Alcohol                   | $\odot$      |  |
| Thinner                             | $\times$     |  |
| Acetone                             | $\times$     |  |
| Trichloroethylene                   | $\times$     |  |
| $\odot$ Usable $\times$ Do not use. |              |  |

NOTE: Influences of ultrasonic cleaning of the LED resin body differ depending on such factors as the oscillator output, size of the PC board and the way in which the LED is mounted. Therefore, ultrasonic cleaning should only be performed after confirming there is no problem by conducting a test under practical.

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#### •OTHERS

- 1) Care must be taken to ensure that the reverse voltage will not exceed the absolute maximum rating when using the LEDs with matrix drive.
- Flashing lights have been known to cause discomfort in people; you can prevent this by taking precautions during use. Also, people should be cautious when using equipment that has had LEDs incorporated into it.
- 3) The LEDs described in this brochure are intended to be used for ordinary electronic equipment (such as office equipment, communications equipment, measurement instruments and household appliances). Consult PARA's sales staff in advance for information on the applications in which exceptional quality and reliability are required, particularly when the failure or malfunction of the LEDs may directly jeopardize life or health (such as for airplanes, aerospace, submersible repeaters, nuclear reactor control systems, automobiles, traffic control equipment, life support systems and safety devices).
- 4) User shall not reverse engineer by disassembling or analysis of the LEDs without having prior written consent from PARA. When defective LEDs are found, the User shall inform PARA directly before disassembling or analysis.
- 5) The formal specifications must be exchanged and signed by both parties before large volume purchase begins.
- 6) The appearance and specifications of the product may be modified for improvement without notice.

